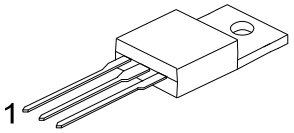
USG10R035H

Preliminary | ***Power MOSFET***

N-CHANNEL SGT ENHANCEMENT POWER MOSFET



TO-220

■ DESCRIPTION

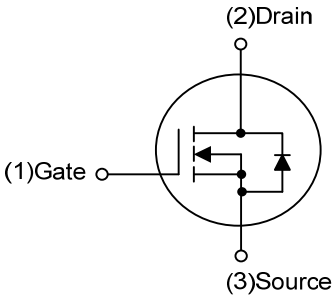
The UTC **USG10R035H** is a N-channel Power MOSFET, it uses UTC's advanced technology to provide the customers with high switching speed and low gate charge, etc.

The UTC **USG10R035H** applies to primary side switch, synchronous rectifier, Motor Drives, etc.

■ FEATURES

* $R_{DS(ON)}$ ≤ 3.5 mΩ @ V_{GS}=10V, I_D=20A
* High Cell Density Trench Technology
* High Power and Current Handling Capability

■ SYMBOL



■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
USG10R035HL-TA3-T	USG10R035HG-TA3-T	TO-220	G	D	S	Tube

Note: Pin Assignment: G: Gate D: Drain S: Source

USG10R035HG-TA3-T

(1)Packing Type	(1) T: Tube
(2)Package Type	(2) TA3: TO-220
(3)Green Package	(3) G: Halogen Free and Lead Free L: Lead Free

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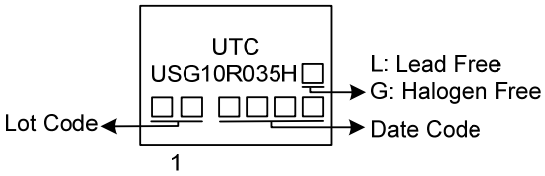
■ MARKING


UTC
USG10R035H
L: Lead Free
G: Halogen Free
Lot Code
Date Code
1

■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	100	V
Gate-Source Voltage		V_{GSS}	±20	V
Drain Current	Continuous	I_D	170	A
	Pulsed (Note 2)	I_{DM}	340	A
Single Pulsed Avalanche Energy (Note 3)		E_{AS}	109	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	1.7	V/ns
Power Dissipation		P_D	190	W
Junction Temperature		T_J	+150	°C
Storage Temperature		T_{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
2. Repetitive Rating: Pulse width limited by maximum junction temperature.
3. L = 0.1mH, I_{AS} = 46.7A, V_{DD} = 50V, R_G = 25Ω, Starting T_J = 25°C.
4. I_{SD} ≤ 30A, di/dt ≤ 200A/μs, V_{DD} ≤ BV_{DSS}, T_J ≤ T_{JMAX}, T_J = 25°C.

■ THERMAL DATA

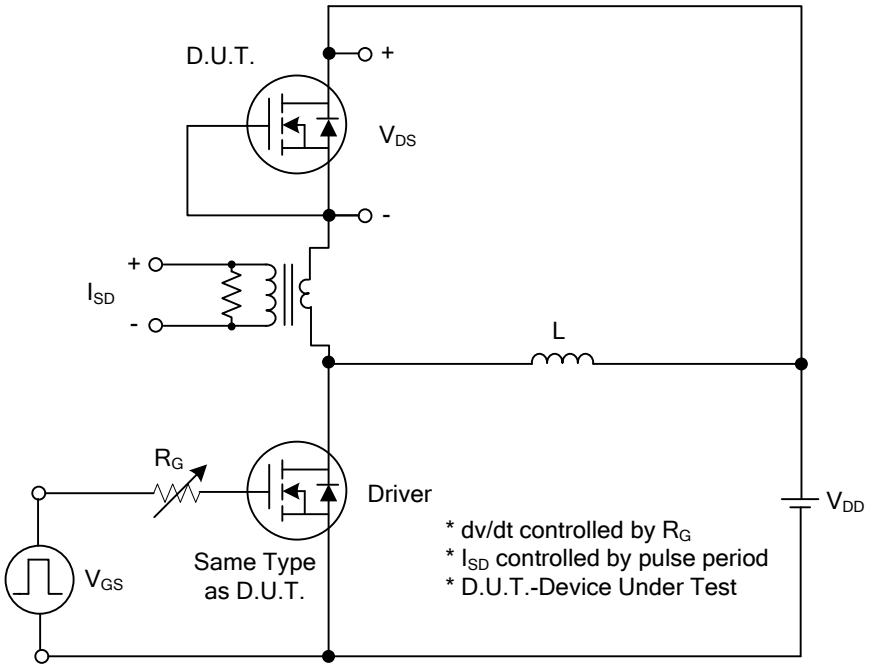
PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	62.5	°C/W
Junction to Case	θ_{JC}	0.66	°C/W

■ ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise specified)

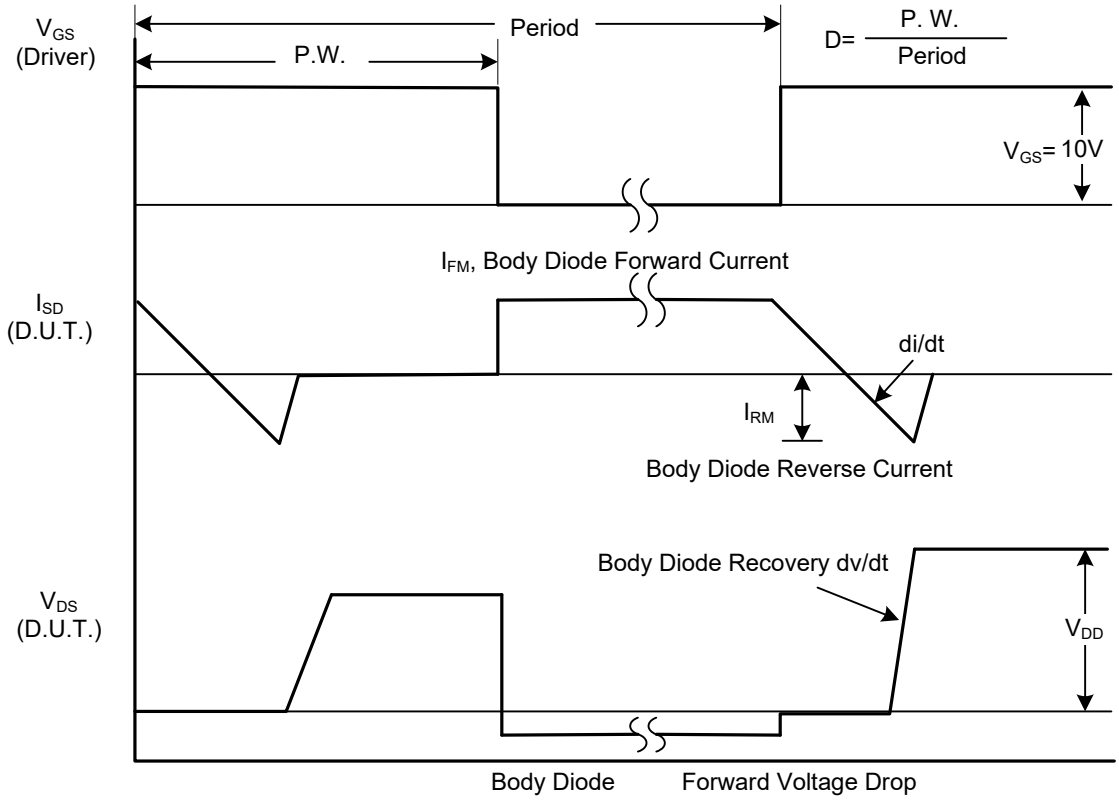
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV_{DSS}	I_D=250μA, V_{GS}=0V	100			V
Drain-Source Leakage Current		I_{DSS}	V_{DS}=100V, V_{GS}=0V			1	μA
Gate-Source Leakage Current	Forward	I_{GSS}	V_{GS}=+20V, V_{DS}=0V			+100	nA
	Reverse		V_{GS}=-20V, V_{DS}=0V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	V_{DS}=V_{GS}, I_D=250μA	2.0		4.0	V
Static Drain-Source On-State Resistance		$R_{DS(ON)}$	V_{GS}=10V, I_D=20A			3.5	mΩ
DYNAMIC PARAMETERS							
Input Capacitance		C_{ISS}	V_{DS}=25V, V_{GS}=0V, f=1.0MHz		7510		pF
Output Capacitance		C_{OSS}			3775		pF
Reverse Transfer Capacitance		C_{RSS}			549		pF
SWITCHING PARAMETERS							
Total Gate Charge		Q_G	V_{DS}=80V, V_{GS}=10V, I_D=170A		179		nC
Gate to Source Charge		Q_{GS}			30		nC
Gate to Drain Charge		Q_{GD}			80		nC
Turn-ON Delay Time		$t_{D(ON)}$	V_{DD}=50V, V_{GS}=10V, I_D=170A, R_G =3Ω		27		ns
Rise Time		t_R			35		ns
Turn-OFF Delay Time		$t_{D(OFF)}$			71		ns
Fall-Time		t_F			45		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Maximum Body-Diode Continuous Current		I_S				170	A
Maximum Body-Diode Pulsed Current		I_{SM}				340	A
Drain-Source Diode Forward Voltage		V_{SD}	I_F=30A, V_{GS}=0V			1.4	V
Body Diode Reverse Recovery Time		t_{rr}	I_S=30A, dI/dt=100A/μs		91		ns
Body Diode Reverse Recovery Charge		Q_{rr}			276		nC

Notes: 1. Pulse Test: Pulse width ≤ 300μs, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS



Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

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